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JAPANESE PATENT OFFICE

PATENT ABSTRACTS OF JAPAN

(11)Publication number: 09162444

(43) Date of publication of application: 20.06.1997

(51)Int.Cl.

H01L 33/00

(21)Application number: 07321755

(71)Applicant:

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(22)Date of filing: 11.12.1995

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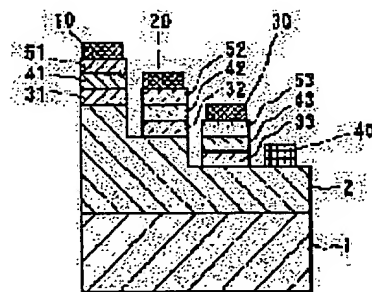
NAKAMURA SHUJI

(54) NITRIDE SEMICONDUCTOR MULTI-COLOR LIGHT EMITTING DEVICE AND ITS PRODUCTION

(57)Abstract:

PROBLEM TO BE SOLVED: To realize a highly fine display by providing a device capable of multi-color light emission by means of one chip and its production method by using a nitride semiconductor.

SOLUTION: After a nitride semiconductor layer having a first active layer 31 is formed on a substrate 1, another nitride semiconductor layer provided with a second active layer 32 whose band gap energy is different from that of the layer 31 is partly grown apart from the layer 31. Thus, since unit light emitting elements including active layers formed of nitride semiconductors of which band gap energies are different from each other are separately formed on the same substrate, multi-color light emission can be realized by only one chip.



LEGAL STATUS

[Date of request for examination] 20.02.1998
[Date of sending the examiner's decision of rejection]
[Kind of final disposal of application other than the
examiner's decision of rejection or application converted
registration]
[Date of final disposal for application]
[Patent number]
[Date of registration]
[Number of appeal against examiner's decision of rejection]
[Date of requesting appeal against examiner's decision of
rejection]
[Date of extinction of right]

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